RoHS COMPLIANT

HALOGEN FREE

Vishay General Semiconductor

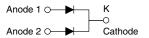
# Dual High Voltage TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.48$  V at  $I_F = 2.5$  A



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#### V10D100C



### LINKS TO ADDITIONAL RESOURCES



**SHA** 

| PRIMARY CHARACTERISTICS                  |                 |  |  |  |
|--|-----------------|--|--|--|
| I <sub>F(AV)</sub> 2 x 5.0 A             |                 |  |  |  |
| V <sub>RRM</sub>                         | 100 V           |  |  |  |
| I <sub>FSM</sub>                         | 100 A           |  |  |  |
| $V_F$ at $I_F$ = 5.0 A ( $T_A$ = 125 °C) | 0.60 V          |  |  |  |
| T <sub>J</sub> max.                      | 150 °C          |  |  |  |
| Package                                  | SMPD (TO-263AC) |  |  |  |
| Circuit configuration                    | Common cathode  |  |  |  |

### **FEATURES**

- AUTOMOTIVE GRADE Trench MOS Schottky technology generation 2 Available
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency operation
- 1, per Meets MSL level J-STD-020. LF maximum peak of 260 °C
- AEC-Q101 gualified available: - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test Polarity: as marked

| <b>MAXIMUM RATINGS</b> ( $T_A = 25$ °C unless otherwise noted)                       |            |                                   |             |      |
|--|------------|-----------------------------------|-------------|------|
| PARAMETER  |            | SYMBOL                            | V10D100C    | UNIT |
| Maximum repetitive peak reverse voltage  |            | V <sub>RRM</sub>                  | 100         | V    |
| Maximum average forward rectified current (fig. 1)                                   | per device | levus.                            | 10          | ^    |
|  | per diode  | IF(AV)                            | 5           | — A  |
| Peak forward surge current 10 ms single half sine-wave<br>superimposed on rated load |            | I <sub>FSM</sub>                  | 100         | А    |
| Voltage rate of change (rated V <sub>R</sub> )                                       |            | dV/dt                             | 10 000      | V/µs |
| Operating junction and storage temperature range                                     |            | T <sub>J</sub> , T <sub>STG</sub> | -40 to +150 | °C   |

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| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                         |                           |                               |      |      |      |  |
|---|-------------------------|---------------------------|-------------------------------|------|------|------|--|
| PARAMETER   | TEST CONDITIONS         |                           | SYMBOL                        | TYP. | MAX. | UNIT |  |
| Instantaneous forward voltage   | I <sub>F</sub> = 2.5 A  | T <sub>A</sub> = 25 °C    | V <sub>F</sub> (1)            | 0.55 | -    | v    |  |
|   | $I_{F} = 5.0 \text{ A}$ |                           |                               | 0.67 | 0.75 |      |  |
|   | I <sub>F</sub> = 2.5 A  | - T <sub>A</sub> = 125 °C |                               | 0.48 | -    |      |  |
|   | I <sub>F</sub> = 5.0 A  |                           |                               | 0.60 | 0.68 |      |  |
| Reverse current at rated $V_R$ per diode  | V <sub>B</sub> = 70 V   | T <sub>A</sub> = 25 °C    | I <sub>R</sub> <sup>(2)</sup> | 2.3  | -    | μA   |  |
|   | $v_{\rm R} = 70$ v      | T <sub>A</sub> = 125 °C   |                               | 2.3  | -    | mA   |  |
|   | V <sub>R</sub> = 100 V  | T <sub>A</sub> = 25 °C    |                               | -    | 500  | μA   |  |
|   | $v_{\rm R} = 100 v$     | T <sub>A</sub> = 125 °C   |                               | 7    | 20   | mA   |  |

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$  Pulse test: Pulse width  $\leq 5\mbox{ ms}$ 

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |            |                         |          |      |
|--|------------|-------------------------|----------|------|
| PARAMETER  |            | SYMBOL                  | V10D100C | UNIT |
| Typical thermal resistance   | per diode  | - R <sub>θJC</sub>      | 3.5      | °C/W |
|  | per device |                         | 2.5      |      |
|  | per device | R <sub>0JA</sub> (1)(2) | 48       |      |

#### Notes

 $^{(3)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$  - junction-to-mount

<sup>(4)</sup> Free air, without heatsink

| ORDERING INFORMATION (Example) |                              |                    |              |               |                                    |
|--------------------------------|------------------------------|--------------------|--------------|---------------|------------------------------------|
| PACKAGE                        | PREFERRED P/N                | UNIT WEIGHT<br>(g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |
| SMPD (TO-263AC)                | V10D100C-M3/I                | 0.55               | I            | 2000/reel     | 13" diameter plastic tape and reel |
| SMPD (TO-263AC)                | V10D100CHM3/I <sup>(1)</sup> | 0.55               | I            | 2000/reel     | 13" diameter plastic tape and reel |

#### Note

(1) AEC-Q101 qualified

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### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

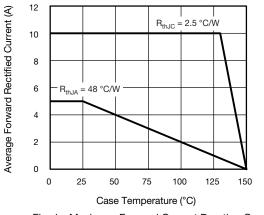


Fig. 1 - Maximum Forward Current Derating Curve

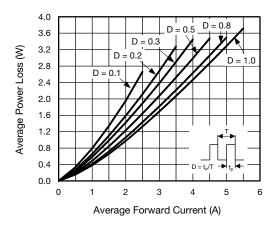


Fig. 2 - Average Power Loss Characteristics

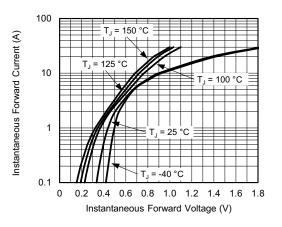


Fig. 3 - Typical Instantaneous Forward Characteristics

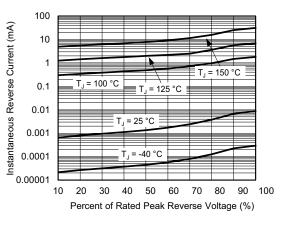


Fig. 4 - Typical Reverse Leakage Characteristics

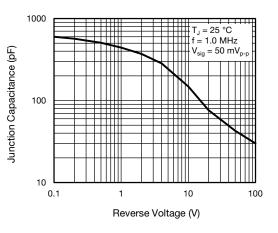


Fig. 5 - Typical Junction Capacitance

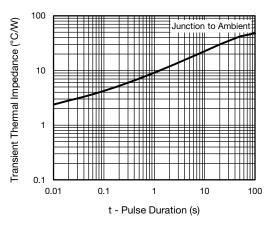


Fig. 6 - Typical Transient Thermal Impedance

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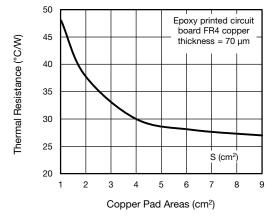
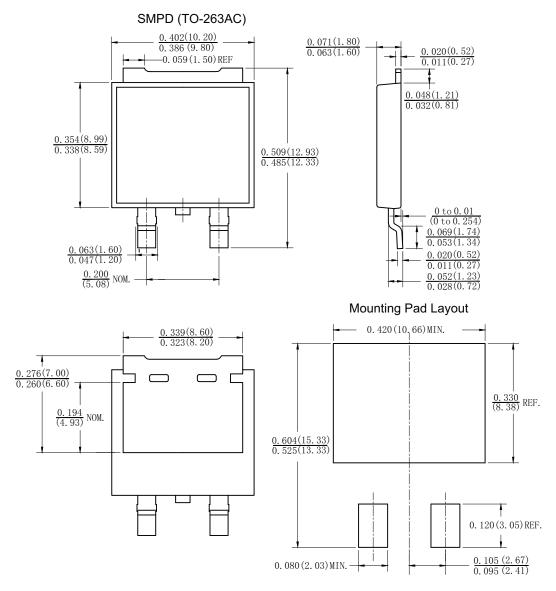


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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